

Protection for Lithium-Ion Batteries (for double protection) Monolithic IC MM3284 Series

Outline

This IC is a double protection IC for lithium battery of 1-cell to 4-cell. It detects the battery voltage for every cell. It includes a timer, eliminating an external capacitor for overcharge detection delay that is used for our conventional ICs, which allows programmable detection delay time.

Features

- 1. Overcharge detection voltage 4.0~4.5V Accuracy $\pm 30\text{mV}$ ($-40\text{~}85^\circ\text{C}$)
- 2. Current consumption ($V_{\text{CELL}}=3.5\text{V}$) 2.5 μA typ.
- 3. Current consumption ($V_{\text{CELL}}=2.5\text{V}$) 2.0 μA typ.
- 4. Maximum rating 28V
- 5. Operating voltage range: 2~24V
- 6. No external capacitance required for delay time
(Delay time is determined by the internal circuit, ranging from 1s to 12s upon request)

Packages

- SOT-26A
SSON-6A

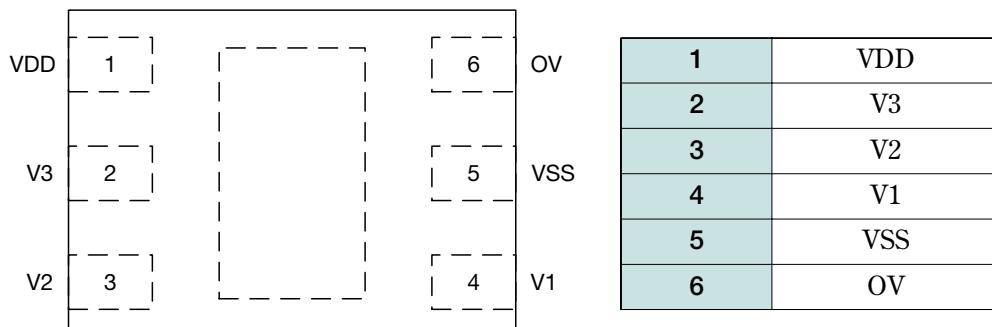
Applications

- 1. Laptop PCs
- 2. Battery powered device

Line-up

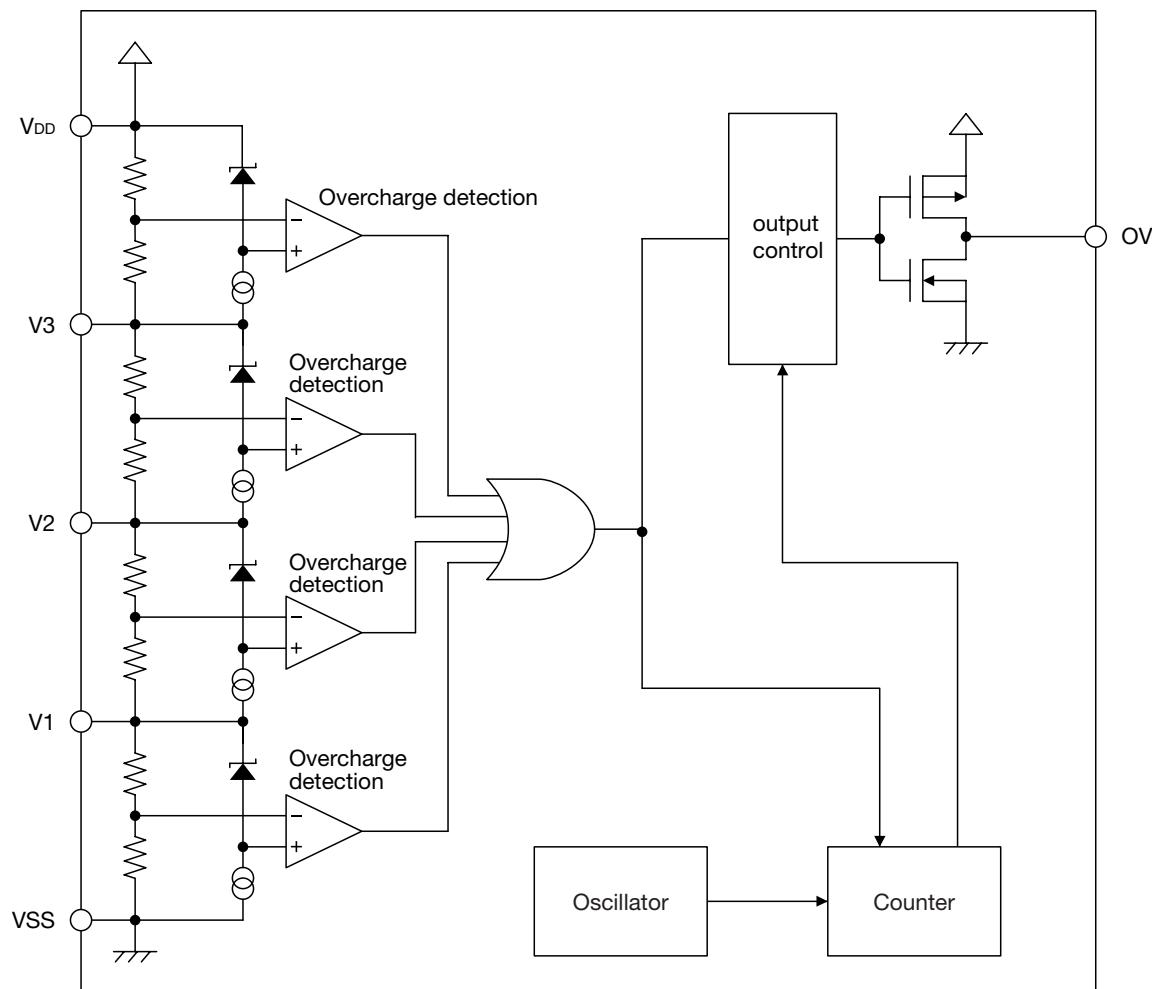
Model	Overcharge Detection Voltage	Overcharge Release Hysteresis Voltage	Overcharge Detection Dead Time
MM3284A	4.350 $\pm 0.03\text{V}$	200 $\pm 60\text{mV}$	1.2s typ.
MM3284B	4.350 $\pm 0.03\text{V}$	1000 $\pm 300\text{mV}$	1.2s typ.
MM3284C	4.350 $\pm 0.03\text{V}$	1000 $\pm 300\text{mV}$	10.0s typ.
MM3284E	4.450 $\pm 0.03\text{V}$	200 $\pm 60\text{mV}$	1.2s typ.
MM3284G	4.450 $\pm 0.03\text{V}$	1000 $\pm 300\text{mV}$	10.0s typ.
MM3284H	4.350 $\pm 0.03\text{V}$	1000 $\pm 300\text{mV}$	5.0s typ.
MM3284I	4.450 $\pm 0.03\text{V}$	1000 $\pm 300\text{mV}$	5.0s typ.
MM3284J	4.400 $\pm 0.03\text{V}$	1000 $\pm 300\text{mV}$	10.0s typ.

Pin Assignment



SSOP-6A
(TOP VIEW)

Block Diagram



Pin Description

Pin No.	Pin name	Input/Output	Functions
1	VDD	INPUT	The input terminal of the power supply for IC and of the positive voltage for V4 cell.
2	V3	INPUT	The input terminal of the positive voltage for V3 cell and of the negative voltage for V4 cell.
3	V2	INPUT	The input terminal of the positive voltage for V2 cell and of the negative voltage for V3 cell.
4	V1	INPUT	The input terminal of the positive voltage for V1 cell and of the negative voltage for V2 cell.
5	VSS	INPUT	The input terminal of the ground of IC and of the negative voltage for V1 cell.
6	OV	OUTPUT	The output terminal of over-charge detection. Output type is CMOS. · Normal mode : "Low" · Overcharge mode : "High"

Absolute Maximum Ratings (Ta=25°C)

Item	Symbol	Ratings	Unit
Storage temperature range	T _{STG}	-5~+125	°C
Operating temperature range	T _{OPR}	-40~+110	°C
Supply voltage	V _{DDmax.}	VSS-0.3~VSS+28	V
OV pin input voltage	V _{Omax.}	VSS-0.3~VDD+0.3	V
Allowable loss	P _d	150	mW

Recommended Operating Conditions (Ta=25°C)

Item	Symbol	Ratings	Unit
Operating temperature range	T _{OPR}	-40~+110	°C
Operating voltage range	V _{OPR}	VSS+2.0~VSS+24	V

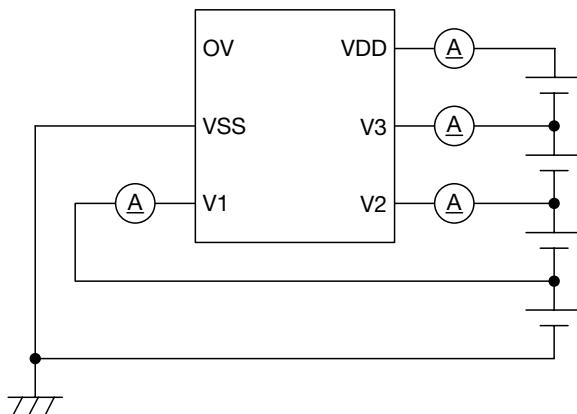
Electrical Characteristics (Except where noted otherwise, Ta=25°C, V_{CELL}=3.5V)

Item	Symbol	Measurement conditions	Min.	Typ.	Max.	Unit	Measuring Circuit
Consumption current 1	I _{DD1}	V _{CELL} =3.5V, I _{OUT} =0mA		2.5	5	µA	A
Consumption current 2	I _{DD2}	V _{CELL} =2.3V, I _{OUT} =0mA		2	4	µA	A
V3 pin input current	I _{V3}	V _{CELL} =3.5V	-300		300	nA	A
V2 pin input current	I _{V2}	V _{CELL} =3.5V	-300		300	nA	A
V1 pin input current	I _{V1}	V _{CELL} =3.5V	-300		300	nA	A
Overcharge detection voltage	V _{CELLU}	Ta=0~+50°C *1 V _{CELL} =3.5V→4.5V	4.320	4.350	4.380	V	B
Overcharge detection voltage	V _{CELLU}	Ta=-40~+85°C *1 V _{CELL} =3.5V→4.5V	4.300	4.350	4.400	V	B
Overcharge detection voltage	V _{CELLU}	Ta=-40~+110°C *1 V _{CELL} =3.5V→4.5V	4.270	4.350	4.430	V	B
Overcharge release voltage	V _{CELLO}	V _{CELL} =4.5V→3.5V	V _{CELLU} 1.2V	V _{CELLU} 1.0V	V _{CELLU} 0.8V	V	B
Overcharge detection dead time	t _{OV}	V _{CELL} =3.5V→4.5V	7.0	10.0	13.0	s	B
OV pin source current	I _{SO OV}	V _{CELL} >V _{CELLU} V _{OV} =V _{IN} -0.5V	20			µA	C
OV pin sink current	I _{SIOV}	V _{OV} =0.5V Ta=-40~110°C *1	20			µA	C
OV pin output voltage H	V _{TH OV H}	V _{CELL} >V _{CELLU} V _{IN} -V _{OV} I _{SO} =20µA			0.5	V	D
OV pin output voltage L	V _{TH OV L}	V _{OV} -V _{SS} I _{SO} =-20µA Ta=-40~110°C *1			0.5	V	D
Voltage of delay time shortening	V _{DS}	V _{CELL} =6V→8V	6.0	7.0	8.0	V	B

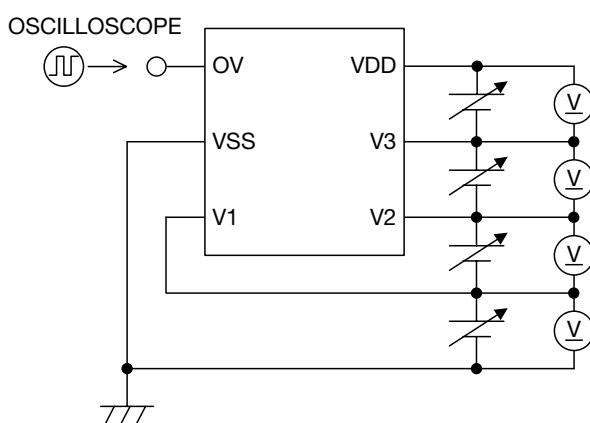
Note1: *1 Guaranteed value

Measuring Circuit

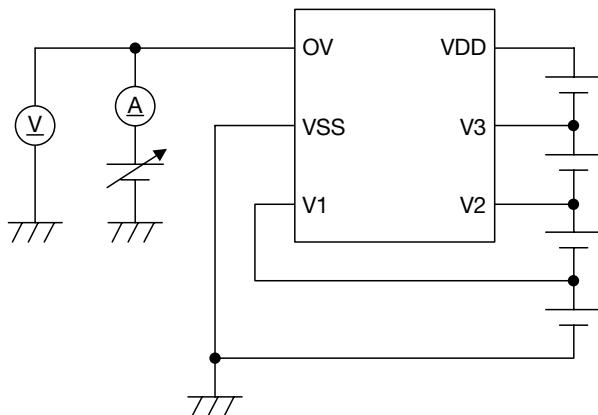
A.



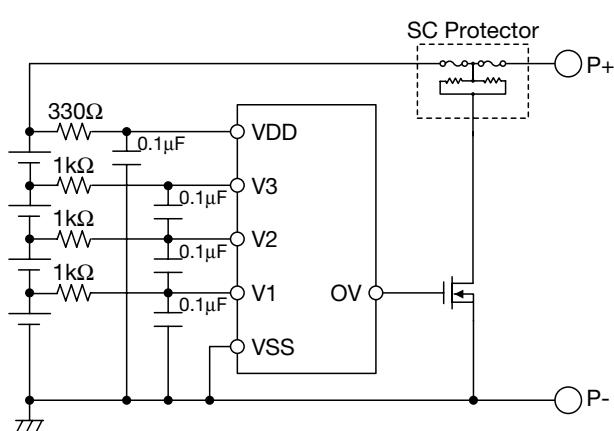
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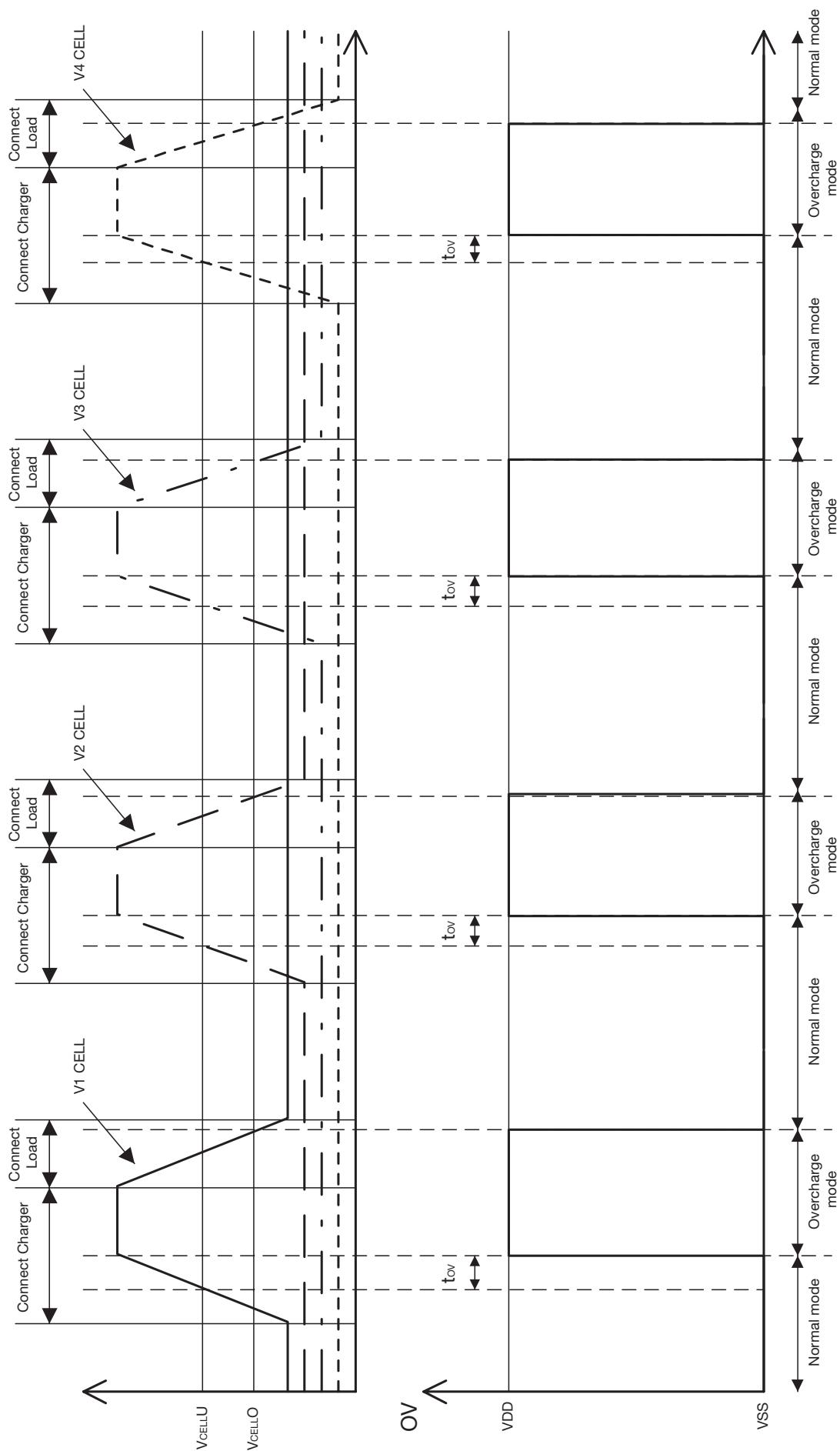
C.



D.

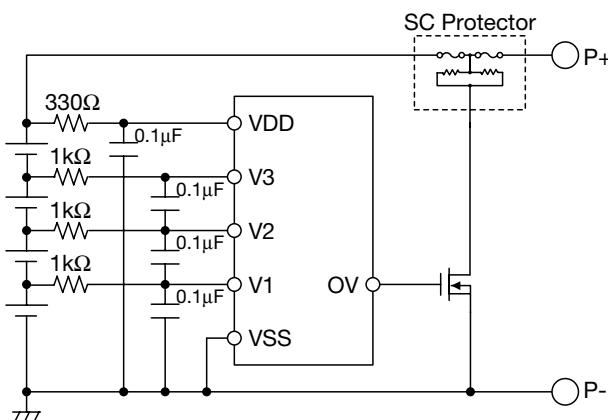


Timing Chart

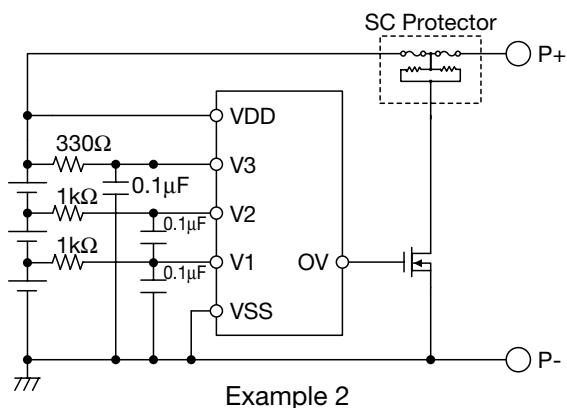
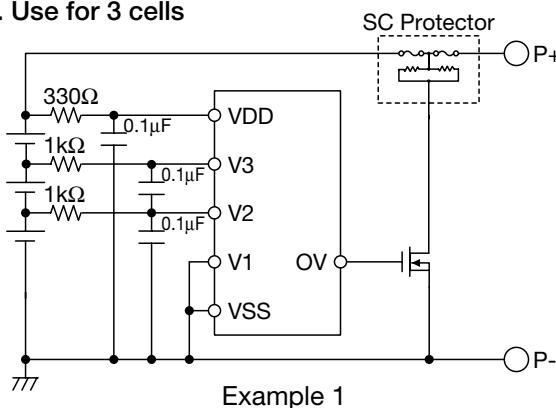


Application Circuit

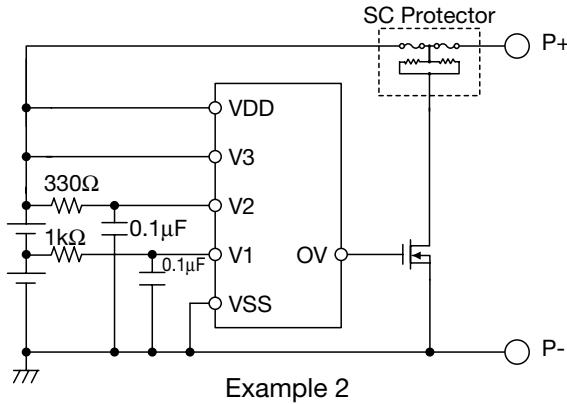
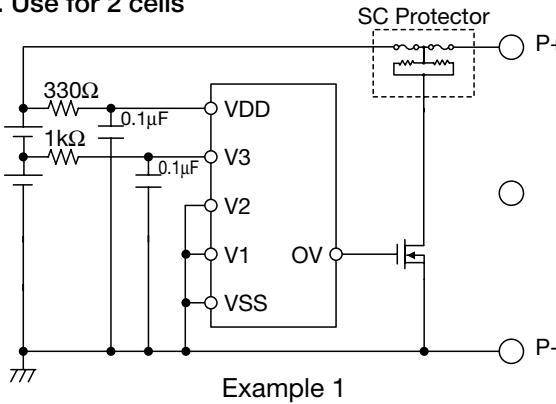
1. Use for 4 cells



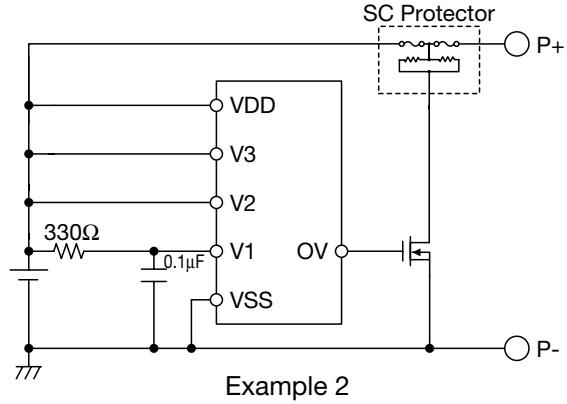
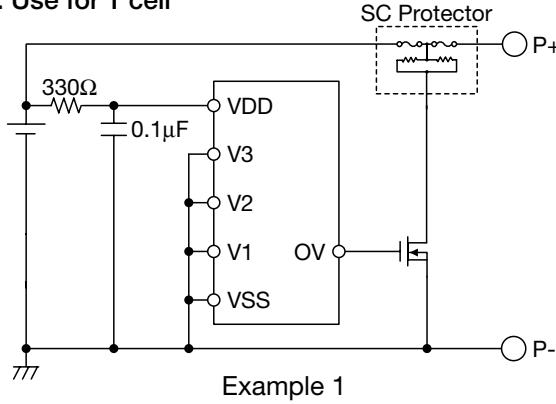
2. Use for 3 cells



3. Use for 2 cells



4. Use for 1 cell



When the battery is connected, 0V and VSS are short-circuited by the jumper, and we recommend the method of removing the jumper that is short-circuited of 0V and VSS when the connection of all cells is completed.

* The fixed number is reference value.